

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



Applicant(s): NAITO et al.

Serial No.: 10/006,135

Filed: December 10, 2001

Title: MANUFACTURING METHOD OF  
SILICON CARBIDE SINGLE CRYSTALS

Atty. Docket No.: 01-235

Group Art Unit: 1775

Examiner: S. STEIN

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DEC 09 2003  
TC 1700

Mail Stop Non-Fee Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Date: November 26, 2003

**AMENDMENT**

Sir:

**Introductory Comments**

In response to the non-Final Office Action dated June 26, 2003, please consider the appended amendments and remarks in the above-referenced application.

**Amendments to the Specification** begin on page 2 of this paper.

**Amendments to the Claims** begin on page 17 of this paper.

**Remarks/Arguments** begin on page 20 of this paper.